



Peak EMI Reducing Solution

Features

- Generates an EMI optimized clock signal at the output.
- Integrated loop filter components.
- Operates with a 3.3V / 2.5V supply.
- · Operating current less than 4mA.
- CMOS design.
- Input frequency: 12MHz
- Generates a 1X low EMI spread spectrum clock of the input frequency.
- Frequency deviation: ±0.4%(Typ) @ 12MHz Input Frequency
- Available in 6L-TSOP (6L-TSOT-23) package.

Product Description

The ASM3P2863A is a versatile spread spectrum frequency modulator designed specifically for a wide range of clock frequencies. The ASM3P2863A reduces electromagnetic interference (EMI) at the clock source, allowing system wide reduction of EMI of all clock dependent signals. The ASM3P2863A allows significant system cost savings by reducing the number of circuit board layers, ferrite beads and shielding that are traditionally required to pass EMI regulations.

The ASM3P2863A uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method.

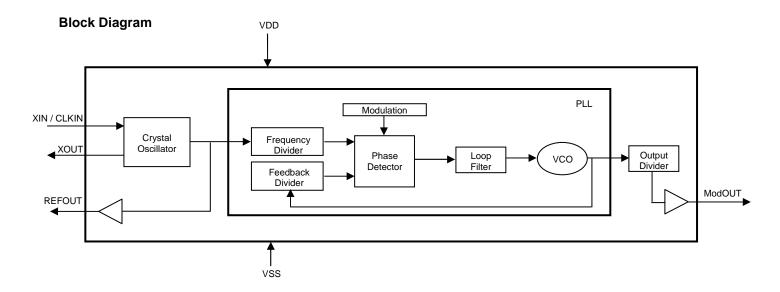
The ASM3P2863A modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, and more importantly, decreases the peak amplitudes of its harmonics. This result in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most frequency generators. Lowering EMI by increasing a signal's bandwidth is called 'spread spectrum clock generation.'

Applications

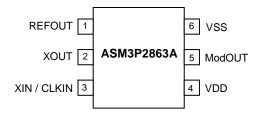
The ASM3P2863A is targeted towards all portable devices with very low power requirements like MP3 players, Notebooks and Digital still cameras.

Key Specifications

Description	Specification
Supply voltages	$V_{DD} = 2.5 V / 3.3 V$
Cycle-to-Cycle Jitter	±200pS (typ)
Output Duty Cycle	45/55% (worst case)
Modulation Rate Equation	F _{IN} /256
Frequency Deviation	±0.4 % (Typ) @ 12MHz



Pin Configuration (6L-TSOP Package)



Pin Description

Pin#	Pin Name	Туре	Description	
1	REFOUT	0	Buffered output of the input frequency.	
2	XOUT	0	Crystal connection. If using an external reference, this pin must be left unconnected.	
3	XIN / CLKIN	I	Crystal connection or external reference frequency input. This pin has dual functions. It can be connected either to an external crystal or an external reference clock.	
4	VDD	Р	Power supply for the entire chip.	
5	ModOUT	0	Spread spectrum clock output.	
6	VSS	Р	Ground connection.	

Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
VDD, V _{IN}	Voltage on any input pin with respect to Ground	-0.5 to +4.6	V
T _{STG}	Storage temperature	-65 to +125	C
Ts	Max. Soldering Temperature (10 sec)	260	C
T_J	Junction Temperature	150	C
T_DV	Static Discharge Voltage	2	KV
. 00	(As per JEDEC STD22- A114-B)	_	1
Note: These are s	stress ratings only and are not implied for functional use. Exposure to absolute maximum ratings f	or prolonged periods of time i	may affec

Operating Conditions

Parameter	Description	Min	Max	Unit
VDD	Supply Voltage	2.375	3.6	V
T _A	Operating Temperature (Ambient Temperature)	0	+70	C
C_L	Load Capacitance		15	pF
C _{IN}	Input Capacitance		7	рF

DC Electrical Characteristics for 2.5V Supply

Symbol	Parameter	Min	Тур	Max	Unit		
V _{IL}	Input low voltage	VSS-0.3		0.8	V		
V_{IH}	Input high voltage	2.0		VDD+0.3	V		
I _{IL}	Input low current			-35	μA		
I _{IH}	Input high current			35	μA		
I _{XOL}	XOUT output low current (@ 0.5V, VDD = 2.5V)		3		mA		
I _{XOH}	XOUT output high current (@ 1.8V, VDD = 2.5V)		3		mA		
V_{OL}	Output low voltage (VDD = 2.5V, I _{OL} = 8mA)			0.6	V		
V _{OH}	Output high voltage (VDD = 2.5V, I _{OH} = 8mA)	1.8			V		
I_{DD}	Static supply current ¹		0.8		mA		
Icc	Dynamic supply current (2.5V, 12MHz and no load)		3		mA		
VDD	Operating voltage	2.375	2.5	2.625	V		
t _{ON}	Power-up time (first locked cycle after power-up)			5	mS		
Z _{OUT}	Output impedance		50		Ω		
Note: 1. XIN	Note: 1. XIN / CLKIN pin is pulled low.						

AC Electrical Characteristics for 2.5V Supply

Symbol	Parameter	Min	Тур	Max	Unit
CLKIN	Input frequency		12		MHz
ModOUT	Output frequency		12		MHz
f _d	Frequency Deviation		±0.4		%
t _{LH} ¹	Output rise time (measured from 0.7V to 1.7V)	0.5	1.5	1.7	nS
t _{HL} ¹	Output fall time (measured from 1.7V to 0.7V)	0.5	1.0	1.2	nS
t _{JC}	Jitter (Cycle-to-Cycle)		±200	±300	pS
t _D	Output duty cycle	45	50	55	%
Note: 1. t _{LH} and t _{HL} are me	easured into a capacitive load of 15pF.				

DC Electrical Characteristics for 3.3V Supply

Symbol	Parameter	Min	Тур	Max	Unit						
V _{IL}	Input low voltage	VSS-0.3		0.8	V						
V _{IH}	Input high voltage	2.0		VDD+0.3	V						
I _{IL}	Input low current			-35	μΑ						
I _{IH}	Input high current			35	μΑ						
I _{XOL}	XOUT output low current (@ 0.4V, V _{DD} = 3.3V)		3		mA						
I _{XOH}	XOUT output high current (@ 2.5V, V _{DD} = 3.3V)		3		mA						
V _{OL}	Output low voltage (VDD = 3.3V, I _{OL} = 8mA)			0.4	V						
V _{OH}	Output high voltage (VDD = 3.3V, I _{OH} = 8mA)	2.5			V						
I _{DD}	Static supply current ¹		1		mA						
Icc	Dynamic supply current (3.3V, 12MHz and no load)		3.5		mA						
VDD	Operating Voltage	3.0	3.3	3.6	V						
t _{ON}	Power-up time (first locked cycle after power-up)			5	mS						
Z _{OUT}	Output impedance		45		Ω						
Note: 1. XIN /	CLKIN pin is pulled low.	·		Note: 1. XIN / CLKIN pin is pulled low.							

AC Electrical Characteristics for 3.3V Supply

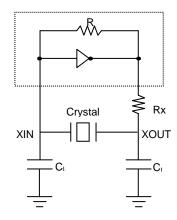
Symbol	Parameter	Min	Тур	Max	Unit	
CLKIN	Input frequency		12		MHz	
ModOUT	Output frequency		12		MHz	
f _d	Frequency Deviation		±0.4		%	
t _{LH} ¹	Output rise time (measured from 0.8 to 2.0V)	0.5	1.4	1.6	nS	
t _{HL} ¹	Output fall time (measured at 2.0V to 0.8V)	0.4	1.0	1.2	nS	
t _{JC}	Jitter (Cycle-to-Cycle)		±200	±300	pS	
t _D	Output duty cycle	45	50	55	%	
Note: 1. t _{LH} and t _{HL} are m	Note: 1. t _{LH} and t _{HL} are measured into a capacitive load of 15pF.					

Crystal Specifications

Fundamental AT cut parallel resonant crystal				
Nominal frequency	12MHz			
Frequency tolerance	±50ppm or better at 25℃			
Operating temperature range	-25℃ to +85℃			
Storage temperature	-40℃ to +85℃			
Load capacitance (C _P)	18pF			
Shunt capacitance	7pF maximum			
ESR	25Ω			

Note: C_L is Load Capacitance and Rx is used to prevent oscillations at overtone frequency of the Fundamental frequency.

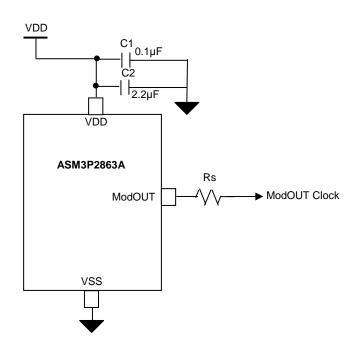
Typical Crystal Interface Circuit



 $C_L = 2^*(C_P - C_S), \\$ Where $C_P = Load$ capacitance of crystal from crystal vendor datasheet.

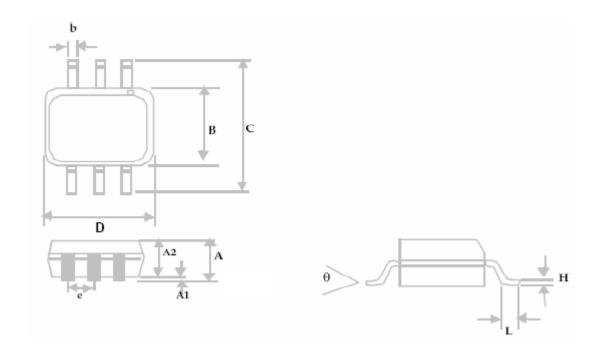
 C_S = Stray capacitance due to C_{IN} , PCB, Trace, etc.

Typical Application Schematic



Package Information

6L-TSOP Package



		Dimensions			
Symbol	Inches		Millim	neters	
	Min	Max	Min	Max	
Α		0.04		1.00	
A1	0.00	0.004	0.00	0.10	
A2	0.033	0.036	0.84	0.90	
b	0.012	0.02	0.30	0.50	
Н	0.005	BSC	0.127 BSC		
D	0.114 BSC		2.90	BSC	
В	0.06 BSC		1.60	BSC	
е	0.0374 BSC		0.950	BSC	
С	0.11 BSC		2.80	BSC	
L	0.0118	0.02	0.30 0.50		
θ	0°	4°	0°	4°	

ASM3P2863A

Ordering Information

Part Number	Marking	Package Type	Temperature
ASM3P2863AF-06OR	V4L	6L-TSOP (6L-TSOT-23), TAPE & REEL, Pb Free	0℃ to +70℃

A "microdot" placed at the end of last row of marking or just below the last row toward the center of package indicates Pb-free.

Licensed under US Patent #5,488,627 and #5,631,921.

Note: This product utilizes US Patent #6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003.

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